## **Question Paper**

**Marks: 100** 

Exam Date & Time: 07-Jan-2019 (10:00 AM - 01:00 PM)

Answer all the questions.

expression.



## MANIPAL ACADEMY OF HIGHER EDUCATION

## SCHOOL OF INFORMATION SCIENCES

FIRST SEMESTER MASTER OF ENGINEERING - ME (VLSI DESIGN) DEGREE EXAMINATION (MAKE-UP) - JANUARY 2019

## Digital Systems and VLSI Design [EDA 613]

**MAKEUP EXAM - JAN 2019** 

1) (10)Explain N-well process with neat diagrams. 2) Explain the thermal oxidation mechanism. (10)3) Compare positive and negative photoresists. (10)4) What are the different ways of photoresist dispensing? (10)5) With diagrams, compare NELT, NELS and HMOS static load (10)inverters. 6) What are the components of dynamic power dissipation? (10)Explain them briefly with the relevant formulae and diagrams. 7) Derive an expression for the short-circuit power dissipation (10) component in a CMOS circuit. Device a method to reduce

What is a structured CMOS design? What are its advantages? Explain the steps in this design with an example.

this component by analyzing each element in this

- Design a fully complimentary single bit full adder using minimum number of transistors. Using this adder, explain how do you construct an adder/subtractor circuit.
- a) What are the various ways of constructing large inverters? Explain with the help of physical layouts. (05) b) What are tristate inverters? What are their advantages? (05)

**Duration: 180 mins.** 

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